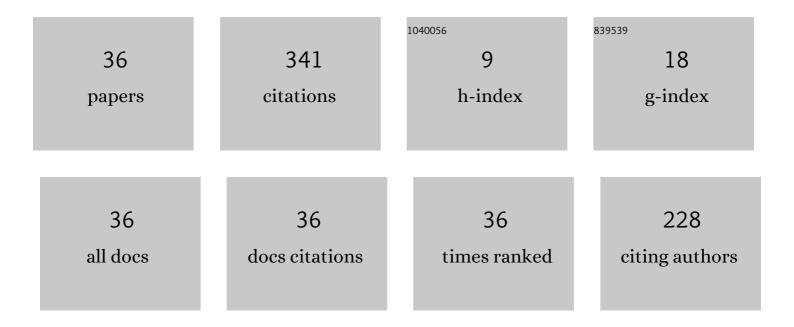
## Tsuneo Yasue

List of Publications by Year in descending order

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TSUNEO VASUE

#	Article	IF	CITATIONS
1	Report on "10th Introductory Course on Practical Vacuum Science and Technologyâ€: Vacuum and Surface Science, 2018, 61, 807-808.	0.1	0
2	Recovery of quantum efficiency in spin-polarized photocathodes by atomic hydrogen cleaning. Ultramicroscopy, 2017, 183, 89-93.	1.9	6
3	Breakdown of the electron-spin motion upon reflection at metal-organic or metal-carbon interfaces. II Physical Review B, 2016, 93, .	3.2	1
4	Temperature Dependence of Lancet Domains in Grain-Oriented Fe-3%Si Steels. IEEE Transactions on Magnetics, 2015, 51, 1-4.	2.1	2
5	Reaction of Sb on In/Si(111) surfaces: Heteroepitaxial InSb(111) formation. Surface Science, 2015, 641, 121-127.	1.9	2
6	Novel multipole Wien filter as three-dimensional spin manipulator. Review of Scientific Instruments, 2014, 85, 043701.	1.3	8
7	Quantitative Analysis of 90° Closure Domains Occurring by Compressive Stress in Fe3%Si(110) Steels. IEEE Transactions on Magnetics, 2014, 50, 1-4.	2.1	4
8	Simulations of magnetic domain patterns on the surface of Co/Ni multilayers. Surface and Interface Analysis, 2014, 46, 1174-1177.	1.8	1
9	In-situ Observation of Graphene Growth on Ultra Flat Metal Substrates. Hyomen Kagaku, 2012, 33, 557-562.	0.0	Ο
10	Macroscopic singleâ€domain graphene sheet on Ni(111). Surface and Interface Analysis, 2011, 43, 1491-1493.	1.8	13
11	Strain of GaAs/GaAsP Superlattices Used as Spin-Polarized Electron Photocathodes, Determined by X-Ray Diffraction. E-Journal of Surface Science and Nanotechnology, 2010, 8, 125-130.	0.4	1
12	Step contrast reversal in LEEM during Pb deposition on W(110). Journal of Physics Condensed Matter, 2009, 21, 314024.	1.8	2
13	Anisotropy of mosaic structure of GaAsP layers grown on GaAs substrates. Physica Status Solidi (A) Applications and Materials Science, 2009, 206, 1785-1789.	1.8	1
14	Mapping of chemical bonding states of Ag/Si(111) with synchrotron radiation photo emission electron microscopy. Surface and Interface Analysis, 2008, 40, 1772-1776.	1.8	7
15	High brightness and high polarization electron source using transmission photocathode with GaAs-GaAsP superlattice layers. Journal of Applied Physics, 2008, 103, .	2.5	49
16	Characterization of spectroscopic photoemission and low energy electron microscope using multipolarized soft x rays at BL17SU/SPring-8. Review of Scientific Instruments, 2007, 78, 066107.	1.3	34
17	STM Study on Initial Te Adsorption on Si(111) 7 * 7 Surface. E-Journal of Surface Science and Nanotechnology, 2006, 4, 406-409.	0.4	5
18	Sb on In/Si(111) processes with dynamically observable LEEM, selected area LEED and chemically analyzed SR-XPEEM. Surface and Interface Analysis, 2006, 38, 1773-1776.	1.8	4

TSUNEO YASUE

#	Article	IF	CITATIONS
19	Angle-dependent neutralization of low-energy alkali ions scattered from alkali-covered Si surfaces. Surface and Interface Analysis, 2005, 37, 159-163.	1.8	0
20	Copper nanostructure formation and structure analysis on hydrogen-terminated Si(111) surface. Surface and Interface Analysis, 2003, 35, 24-28.	1.8	3
21	Recent Development and Application of LEEM/PEEM. Dynamic Observation and Structure Analysis of Cu Nano-structure on Si(III) Surfaces Hyomen Kagaku, 2002, 23, 271-276.	0.0	2
22	Dynamic observations of the formation of thin Cu layers on clean and hydrogen-terminated Si(111) surfaces. Surface Science, 2001, 480, 118-127.	1.9	16
23	LEEM observation of formation of Cu nano-islands on Si( 111 ) surface by hydrogen termination. Surface Science, 2001, 493, 381-388.	1.9	23
24	DYNAMIC OBSERVATION AND STRUCTURE ANALYSIS OF NANOSTRUCTURES OF <font>Cu</font> ON <font>Si</font> (111) BY LOW ENERGY ELECTRON MICROSCOPY. , 2001, , .		0
25	DYNAMIC LEEM OBSERVATION OF CU NANOSTRUCTURE FORMATION PROCESSES ON Si(111) WITH HYDROGEN. Surface Review and Letters, 2000, 07, 595-599.	1.1	6
26	Secondary ion emission processes of sputtered alkali ions from alkali/Si(100) and Si(111). Surface Science, 2000, 460, 214-222.	1.9	20
27	High depth resolution analysis of "5 × 5―structure with medium energy ion scattering. Nuclear Instruments & Methods in Physics Research B, 1998, 136-138, 1086-1091.	1.4	7
28	Model of leakage characteristics of (Ba, Sr)TiO3 thin films. Applied Physics Letters, 1998, 73, 954-956.	3.3	82
29	Hydrogen Termination Effect on the Growth of Cu/Si(111) Hyomen Kagaku, 1996, 17, 401-405.	0.0	1
30	Medium energy ion scattering and STM studies on. Nuclear Instruments & Methods in Physics Research B, 1995, 99, 495-498.	1.4	9
31	Surface structure of Cu/Si(111) at high temperature. Surface Science, 1995, 331-333, 506-510.	1.9	15
32	Growth Process and Secondary Ion Emission for Na/Si(111) Shinku/Journal of the Vacuum Society of Japan, 1995, 38, 421-423.	0.2	0
33	Growth Process of Cu/Si(111) at High Temperature with STM Shinku/Journal of the Vacuum Society of Japan, 1995, 38, 428-430.	0.2	0
34	Analysis of Cu/Si(111)-"5*5" at High Temperature with Medium Energy Ion Scattering Shinku/Journal of the Vacuum Society of Japan, 1995, 38, 424-427.	0.2	0
35	Metal Film Growth on Si Crystals with Medium Energy Ion Scattering Hyomen Kagaku, 1993, 14, 391-396.	0.0	0
36	Electron stimulated desorption from hydrogen and alkali adsorbed Si(111) surface. Vacuum, 1990, 41, 561-563.	3.5	17